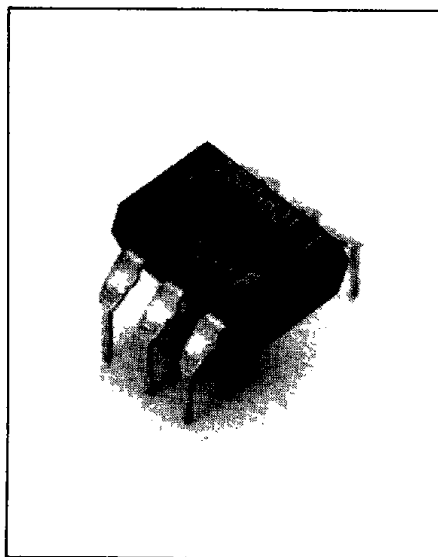


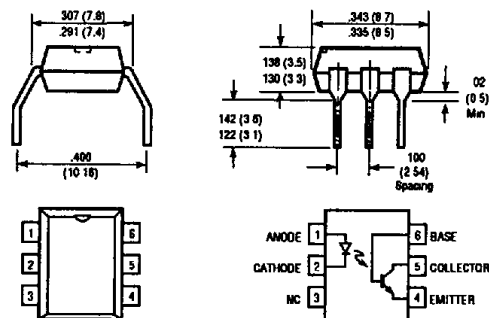
SIEMENS**SFH 601G SERIES****PHOTOTRANSISTOR
OPTOCOUPLER****T-41-83****FEATURES**

- **Wide Lead Spacing**
- **Highest Quality Premium Device**
- **Long Term Stability**
- **High Current Transfer Ratios, 4 Groups**
 - SFH 601G-1, 40 to 80%
 - SFH 601G-2, 63 to 125%
 - SFH 601G-3, 100 to 200%
 - SFH 601G-4, 160 to 320%
- **5300 Volt Isolation (1 Minute)**
- **Storage Temperature** -40° to $+150^{\circ}\text{C}$
- **V_{CEsat} 0.25 (< 0.4) Volt**
- **$I_F = 10$ mA, $I_C = 2.5$ mA**
- **UL Approval #E52744**
- **VDE Approval #0883, #0805, #0806**
- **VDE Approval #0884 (Optional with Option 1, add -X001 suffix)**
- **CECC Approved**

DESCRIPTION

The SFH 601G is an optocoupler that is comprised of a GaAs LED emitter which is optically coupled with a silicon planar phototransistor detector. The component is packaged in a plastic plug-in case 20 AB DIN 41866. The coupler transmits signals between two electrically isolated circuits. The potential difference between the circuits to be coupled is not allowed to exceed the maximum permissible insulating voltage.

Package Dimensions in Inches (mm)

**Maximum Ratings**

Reverse Voltage (V_R)	6 V
Forward Current (I_F)	60 mA
Surge Current (I_{FS}), $t_p = 10 \mu\text{s}$	2.5 A
Power Dissipation (P_{TOT})	100 mW

Detector (Silicon Phototransistor)

Collector-Emitter Voltage (V_{CEO})	70 V
Emitter-Base Reverse Voltage (V_{EB0})	7 V
Collector Current (I_C)	50 mA
Collector Current (I_{CS}), $t = 1$ ms	100 mA
Power Dissipation (P_{TOT})	150 mW

Coupler

Storage Temperature (T_{stor})	-40 to $+150^{\circ}\text{C}$
Ambient Temperature (T_{amb})	-40 to $+100^{\circ}\text{C}$
Junction Temperature (T_j)	100°C
Soldering Temperature (T_L), 10 s Max	260°C
Isolation Test Voltage (V_{IS}), 1 Min (between emitter and detector referred to standard climate 23/50 DIN 50014)	5300 VDC
Tracking Resistance	Min 8.2 mm
Air Path	Min 8 mm

Tracking ResistanceGroup III (KC = > 600) in accordance with VDE 0110 § 6

Table 3 and DIN 53480/VDE 0303, Part 1

As to nominal isolation voltage DIN 57883 or VDE 0883 applies

Isolation Resistance (R_{IS}), @ $V_{IS} = 500$ V $10^{11} \Omega$ **Climatic Conditions**

DIN 40040, humidity Class F

FlammabilityDIN 57471 or VDE 0471, Part 2,
of April 1975 or MIL202E, Method 11 A**Characteristics ($T_{amb} = 25^{\circ}\text{C}$)****Emitter (GaAs LED)**

Forward Voltage (V_F), $I_F = 60$ mA	1.25 (≤ 1.65) V
Breakdown Voltage (V_{BR}), $I_R = 100 \mu\text{A}$	30 (≥ 6) V
Reverse Current (I_R), $V_R = 6$ V	0.01 (≤ 10) μA
Capacitance (C_D) ($V_R = 0$ V, $f = 1$ MHz)	40 pF
Thermal Resistance (R_{thJamb})	750 K/W

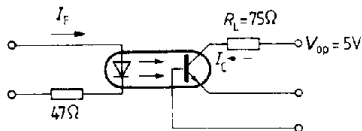
Detector (Silicon Phototransistor)

Capacitance ($V_{CE} = 5$ V, $f = 1$ MHz)	
C_{CE}	6.8 pF
C_{CB}	8.5 pF
C_{EB}	11 pF
Thermal Resistance (R_{thJamb})	500 K/W

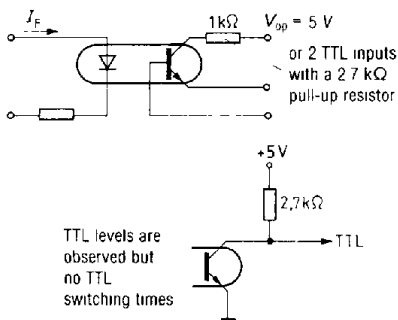
Characteristics (Continued)**Coupler**Collector-Emitter Saturation Voltage (V_{CEsat}) $(I_F = 10 \text{ mA}, I_C = 2.5 \text{ mA}) \dots \dots \dots 0.25 (< 0.4) \text{ V}$ Coupling Capacitance (C_K) $\dots \dots \dots 0.30 \text{ pF}$

The optocouplers are grouped according to their current transfer ratio I_C/I_F at $V_{CE}=5 \text{ V}$, marked by dash numbers

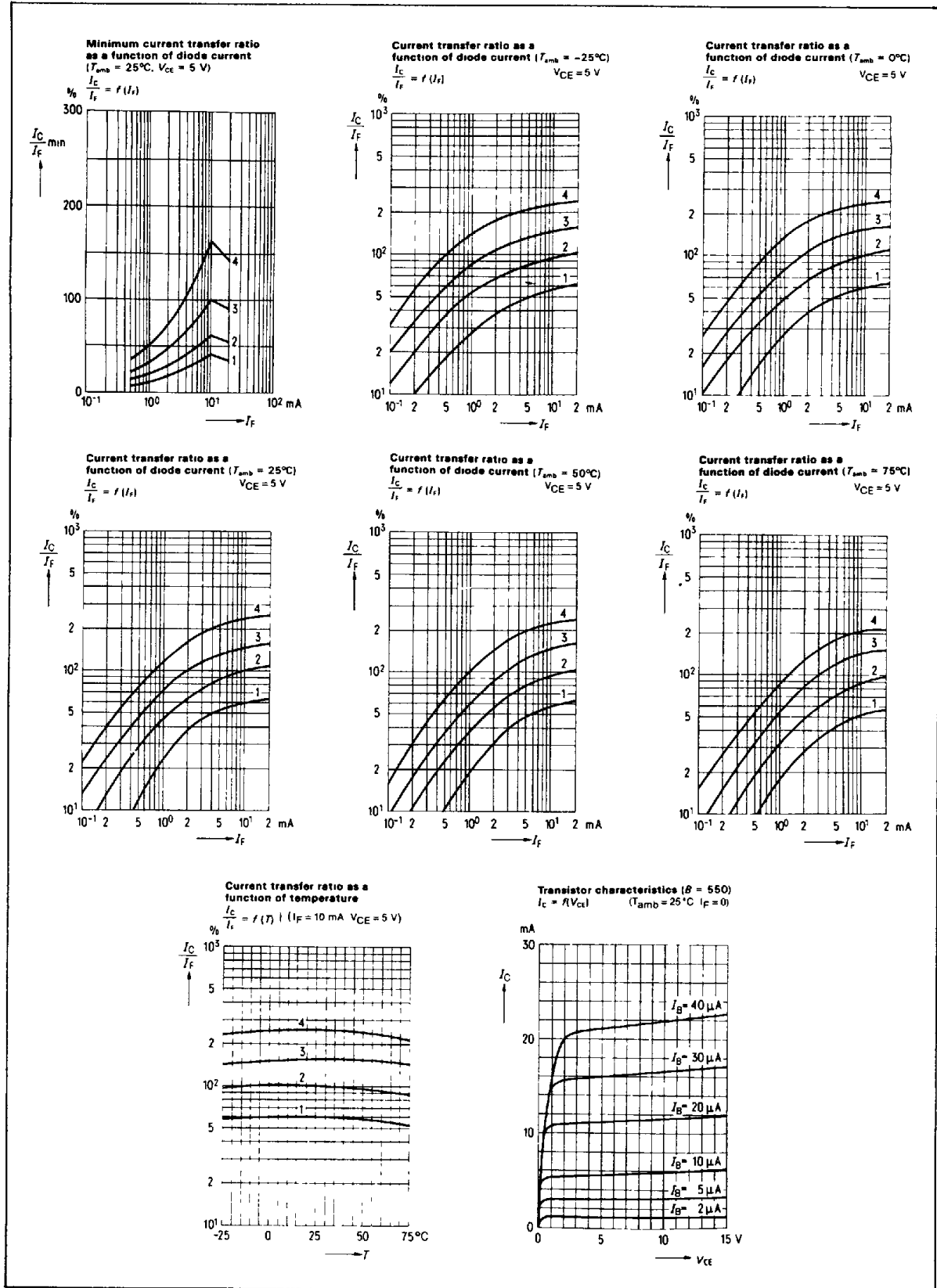
	-1	-2	-3	-4	
I_C/I_F ($I_F=10 \text{ mA}$)	40-80	63-125	100-200	160-320	%
I_C/I_F ($I_F=1 \text{ mA}$)	30(>13)	45(>22)	70(>34)	90(>56)	%
Collector-Emitter Leakage Current ($V_{CE}=10 \text{ V}$) (I_{CED})	2 (≤ 50)	2 (≤ 50)	5 (≤ 100)	5 (≤ 100)	nA

Linear Operation (without saturation) $I_F=10 \text{ mA}, V_{Op}=5 \text{ V}, T_{amb}=25^\circ\text{C}$

Load Resistance	R_L	75	Ω
Turn-On Time	t_{on}	3.0 (≤ 5.6)	μs
Rise Time	t_r	2.0 (≤ 4.0)	μs
Turn-Off Time	t_{off}	2.3 (≤ 4.1)	μs
Fall Time	t_f	2.0 (≤ 3.5)	μs
Cut-Off Frequency	F_{co}	250	kHz

Switching Operation (with saturation)

Group	-1 ($I_F=20 \text{ mA}$)	-2 and -3 ($I_F=10 \text{ mA}$)	-4 ($I_F=5 \text{ mA}$)	
Turn-On Time t_{on}	3.0 (≤ 5.5)	4.2 (≤ 8.0)	6.0 (≤ 10.5)	μs
Rise Time t_r	2.0 (≤ 4.0)	3.0 (≤ 6.0)	4.6 (≤ 8.0)	μs
Turn-Off Time t_{off}	18 (≤ 34)	23 (≤ 39)	25 (≤ 43)	μs
Fall Time t_f	11 (≤ 20)	14 (≤ 24)	15 (≤ 26)	μs
V_{CESAT}	0.25 (≤ 0.4)			V



SFH 601G

